NSN 5962-01-351-3810

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-351-3810					
Overall Length:					
1.280 inches					
Overall Height:					
0.400 inches					
Body Length:					
1.280 inches					
Body Width:					
Between 0.220 inches and 0.310 inches					
Body Height:					
Between 0.140 inches and 0.185 inches					
Maximum Power Dissipation Rating:					
1.2 watts					
Operating Tempurature Range:					
-55.0/+125.0 degrees celsius					
Storage Tempurature Range:					
-65.0/+150.0 degrees celsius					
End Application:					
Satellite communications terminal an/usc-3 (v) 1					
Features Provided:					
High impedance and monolithic and w/clock and bidirectional and bipolar					
Inclosure Material:					
Ceramic					
Inclosure Configuration:					
Dual-in-line					
Output Logic Form:					
Transistor-transistor logic					
Input Circuit Pattern:					
20 input					
Case Outline Source And Designator:					
D-9 mil-m-38510					
Current Rating Per Characteristic:					
165.00 milliamperes reverse current, dc absolute					
Terminal Surface Treatment:					
Solder					
Product Name:					
And-or invert gate array					
Voltage Rating And Type Per Characteristic:					
-0.5 volts power source and 12.0 volts power source					
Time Rating Per Chacteristic:					
35.00 nanoseconds propagation delay time, high to low level output and 33.00 nanoseconds propagation delay time, low to high level					
output					
Memory Device Type:					

Pal

NSN 5962-01-351-3810

Memory Microcircuit - Page 2 of 2



T		Data	D	ıment
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96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0